

Preliminary

TOSHIBA Photocoupler GaAłAs IRED & Photo-IC

TLP716

Digital Isolation for A/D,D/A Conversion. High Speed Line Receiver. Microprocessor System Interfaces. Plasma display panel.

The TOSHIBA TLP716 consists of a GaAłAs light emitting diode and a high speed photodetector. This unit is 6-lead SDIP. TLP716 is 50% smaller than 8PIN DIP and has suited the safety standard reinforced insulation class. So mounting area in safety standard required equipment can be reduced.

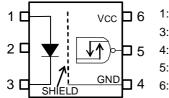
- Inverter Logic (totempole output)
- Package Type : SDIP6
- Guaranteed Performance Over Temperature : -40~100°C
- Power Supply Voltage : 4.5~5.5V
- Input Thresholds Current : IFHL=6.5mA(max.)
- Propagation delay Time (tpHL/ tpLH) : 75ns(max.)
- Switching speed : 20MBd(typ.) (NRZ)
- Common mode transient immunity : 10kV/us
- Isolation Voltage : 5000Vrms
- Construction Mechanical Rating

	7.62 mm pich standard type	10.16 mm pich TLPXXXF type
Creepage Distance	7.0 mm (min)	8.0 mm (min)
Clearance	7.0 mm (min)	8.0 mm (min)
Insulation Thickness	0.4 mm (min)	0.4 mm (min)

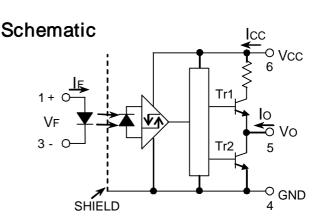
Truth Table

Input	LED	Tr1	Tr2	Output
Н	ON	OFF	ON	L
L	OFF	ON	OFF	Н

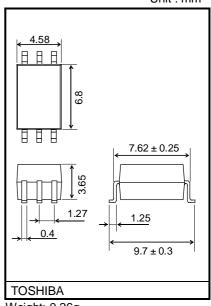
Pin Configuration (top view)







A 0.1uF bypass capacitor must be connected between pin6 and 4. (See Note3)



Weight: 0.26g

Unit : mm

Maximum Ratings (Ta=25°C)

	CHARACTERISTIC	SYMBOL	RATING	UNIT
	Forward Current	lF	20	mA
LED	Peak Transient Forward Current (Note1)	IFPT		А
	Reverse Voltage	VR	5	V
₽	Output Current	ю	10	mA
010	Output Voltage	Vo	6	V
Ĕ	Output Cultent Output Voltage Supply Voltage		6	V
ä	Output power dissipation	PO	40	mW
Oper	ating Temperature Range	Topr	-40~100	°C
Stora	ige Temperature Range	Tstg	-55~125	°C
Lead	Solder Temperature(10s)	Tsol	260	°C
	tion Voltage (C,1min.,R.H.≤60%,Ta=25°C) (Note2)	BVs	5000	Vrms

Note1 : Pulse width PW≤10us,300pps.

- Note2 : Device Considered a two terminal device : pins 1,2 and 3 shorted together and pins 4,5 and 6 shorted together.
- Note3 : A ceramic capacitor(0.1 μ F) should be connected from pin 6 to pin 4 to stabilize the operation of the high gain linear amplifier. Failure to provide the bypassing may impair the switching property.

The total lead length between capacitor and coupler should not exceed 1 cm.

Recommended Operating Conditions

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT
Input Current, ON	IF(ON)	8	12	18	mA
Input Voltage , OFF	VF(OFF)	0		0.8	V
Supply Voltage	VCC	4.5	5	5.5	V
Operating Temperature	Topr	-40		100	°C

The correlation between input current and switching speed and drive circuit (reference information).

Input Current (IF)	TEST CIRCUIT	Typical Switching Speed
12mA	1 (Page 4)	18 – 20 MBd
8mA	1 (Page 4)	16 – 18 MBd
8mA	2 (Page 4,With Speed up capacitor)	20 – 22 MBd

Unless otherwise specified, Ta=-40 to 100°C, VCC=4.5~5.5V)								
CHARACTERISTIC	SYMBOL	CONDITION	MIN.	TYP.	MAX.	UNIT		
Input Forward Voltage	VF	IF=10mA ,Ta=25°C		1.65	1.8	V		
Temperature Coefficient of Forward Voltage	ΔVF/ΔTa	IF=10mA		-2.0	_	mV/°C		
Input Reverse Current	IR	VR=5V,Ta=25°C	_	—	10	μA		
Input Capacitance	Ст	V=0V,f=1MHz,Ta=25°C	_		_	pF		
Logic Low Output Voltage	VOL	IOL=1.6mA, IF=12mA,VCC=5V	_	—	0.4	V		
Logic High Output Voltage	VOH	IOH=-0.02mA , VF=1.05V,VCC=5V	4.0	—	—	V		
Logic Low Supply Current	ICCL	IF=12mA		—	5.0	mA		
Logic High Supply Current	ICCH	VF=0V (Note4)		_	5.0	mA		
Input Current Logic Low Output	IFHL	IO=1.6mA,VO<0.4V		_	6.5	mA		
Input Voltage Logic High Output	VFLH	IO=-0.02mA,VO>4.0V	0.8	_	_	V		

Electrical Characteristics

(Unless otherwise specified, Ta=-40 to 100°C,Vcc=4.5~5.5V)

*All typical values are at Ta=25°C,VCC=5V , IF(ON)=12mA unless otherwise specified

Note4 : The Photodetector needs VCC of 4.5V or more for the stability operation.

In the VCC domain not more than this, since ICCH may increase in part, please use it after checking operation at the time of power supply current, power supply ON, and OFF.

Isolation Characteristics (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Capacitance input to output	CS	VS = 0V , f = 1MHz (Note 2)	_	0.8	_	pF
Isolation resistance	R _S	R.H. ≤ 60%,V _S = 500V (Note 2)	1×10 ¹²	10 ¹⁴		Ω
		AC,1 minute	5000	_	_	V _{rms}
Isolation voltage	BVS	AC,1 second,in oil	—	10000	_	Vdc
		DC,1 minute,in oil	—	10000	-	Vuc

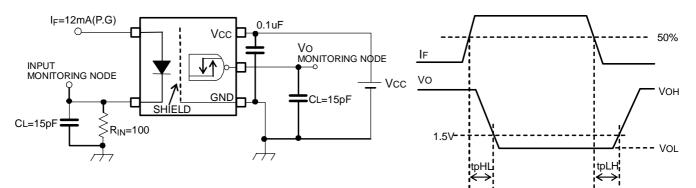
Switching Characteristics (Unless otherwise specified, Ta= -40 to 100 , VCC=4.5~5.5V)

	poomoa	, iu - i		, voo=+.o∞c				
CHARACTERISTIC	SYMBOL	TEST -CIRCUIT	CON	DITION	MIN.	TYP.	MAX.	UNIT
propagation Delay Time to Logic High output	tpLH	1	IF=0→12mA	RIN=100Ω CL=15pF	_		75	ns
propagation Delay Time to Logic Low output	tpHL	1	IF=12→0mA	(Note 5)	—	_	75	ns
propagation Delay Time to Logic High output	tpLH	2	V _{IN} =5→0V (IF=8→0mA)	R _{IN} =430Ω C _{IN=} 33pF	—		65	ns
propagation Delay Time to Logic Low output	tpHL	2	V _{IN} =0→5V (IF=0→8mA)	CL=15pF (Note 5)	_		65	ns
Switching Time Dispersion between ON and OFF	tpHL- tpLH		R _{IN} =100Ω, CL	_=15pF (Note 5)	—		45	ns
Output Rise Time	tr	1	IF=12→0mA	R _{IN} =100Ω CL=15pF	_	15	_	ns
Output Fall Time	tf		IF=0→12mA	(Note 5)	—	15	—	ns
Common Mode transient Immunity at High Level Output	СМН	3	VCM=1000Vp- VO(Min)=4V,Ta		-10000	_	_	V/us
Common Mode transient Immunity at Low Level Output	CML	3	VCM=1000Vp- VO(Max)=0.4∖		10000	_	_	V/us

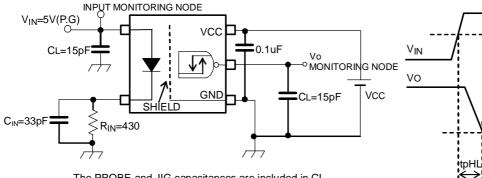
*All typical values are at Ta=25°C

Note 5 : Capacity of a probe and a wire.

TEST CIRCUIT 1 : tpLH , tpHL



TEST CIRCUIT 2 : tpLH , tpHL



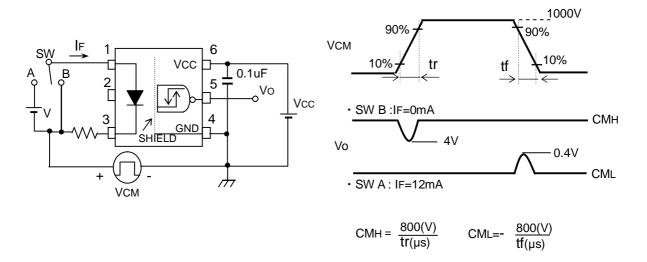
The PROBE and JIG capacitances are included in CL. $(\mbox{P.G})$: Pulse Generatior

tpLH

50%

νон

1.5V ---- VOL TEST CIRCUIT 3 : CMH , CML



 CM_L (CM_H) is the maximum rate of rise (fall) of the common mode voltage that can be sustained with the output voltage in the low (high) state.

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